

Performance of CVD Diamond Detectors Irradiated by Carbon Beams

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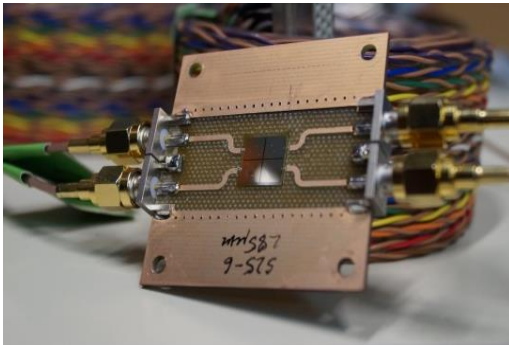
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LNS 2015: Radiation Hardness Tests



IC

Removable (low rate only)

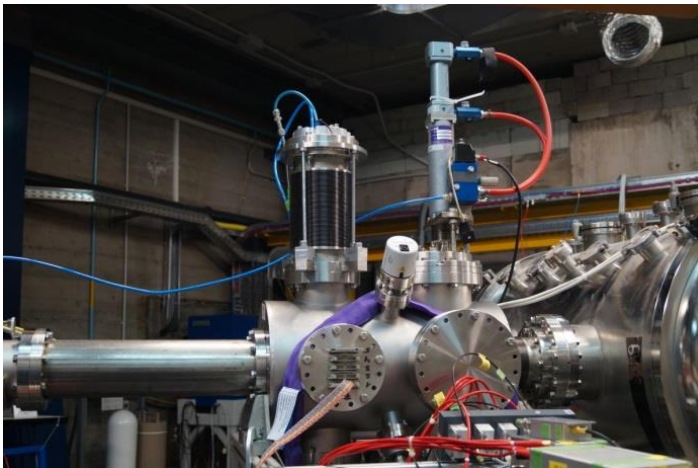


1 x SC CVD
Area: 2x2 mm²
Bias: +100 V
Electrodes: Au 100 nm



1 x 4 Quad PC CVD
Area: 10x10 mm²
Bias: +300 V
Electrodes: Cr/Au, 50/150 nm

62 MeV/u ¹²C @ 2 pA



Schlemme et al. 2017 under preparation.

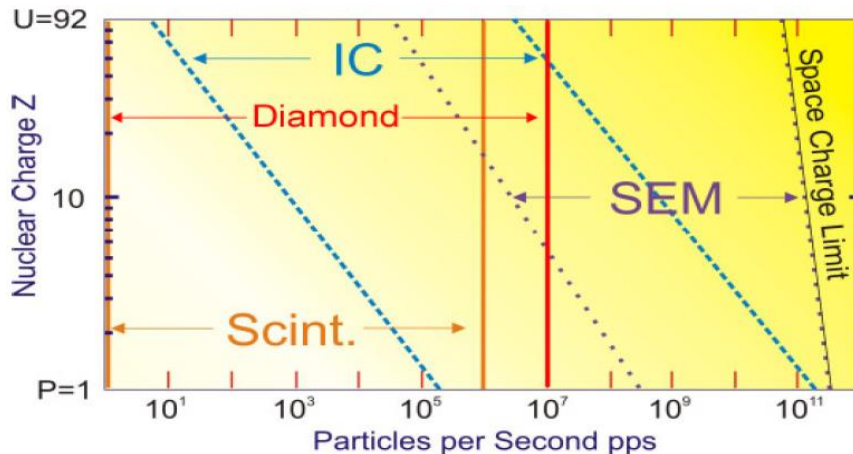
Summary:

- ❑ Unchanged signal properties of the pcCVD DD after 40 hours of irradiation;
- ❑ Variation in the signal properties of the scCVD DD after 12 hours of irradiation;
- ❑ Deposited Dose = 1.8×10^6 Gy (¹²C@62 MeV/u) equivalent to ~ 400 days of operation at Super-FRS;
- ❑ Other characteristics: $\sigma < 45$ ps; *rate* > 500 Hz/mm² [F. Schirru et al., J. Phys. D: Appl. Phys. **49** (2016)].

Super-FRS requirements fully met.

LNS 2017: Motivation

A new particle detector combination (PDC) is under development at GSI. The system will be used to measure the expected high primary beam intensities at FAIR (up to a factor of 10-100 over present) and the consequently increasing intensities of radioactive beams produced at the Super-FRS.



In its present design, the PDC is made up of three different detectors able to cover the wide range of particle rates.

- ☐ DDs [Lower Rates]
- ☐ IC [Medium Rates]
- ☐ SEETRAM [Higher Rates]

Why diamond detectors?

- ☐ In principle, ability to work at higher particle rates (up to 10⁷ particles/s);
- ☐ Radiation Hardness (pcCVD DD);
- ☐ Material available in larger sizes (pcCVD DD).

LNS 2017: The Goals

- ❑ Study of the response and calibration of the DDs, IC, SEETRAM by means of 62 MeV/u ^{12}C beams at different rates between 10^3 - 10^{10} Hz.

In addition...

- ❑ Verify the correct functioning of the DDs for $E > |1| \text{ V}/\mu\text{m}$;
- ❑ Verify any evidences of radiation damages on the scCVD device;
- ❑ Calculate the efficiency ratio of the pcCVD/scCVD DDs;
- ❑ Compare the DDs performance by using two different preamplifiers;
- ❑ Compare the DDs performance by using two different cable lengths.

Extra Task...

- ❑ Evaluate the x-rays response of the DDs before and after performing the PDC test.

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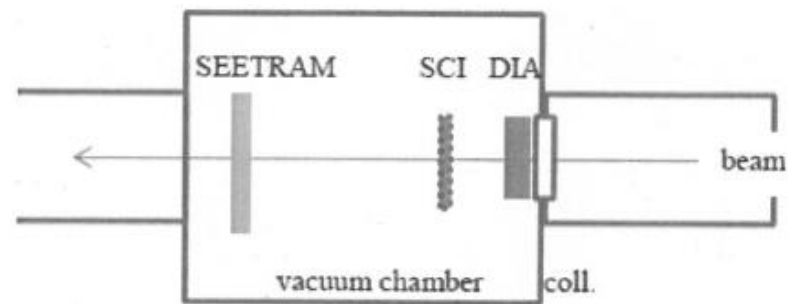
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Experimental Setup @LNS



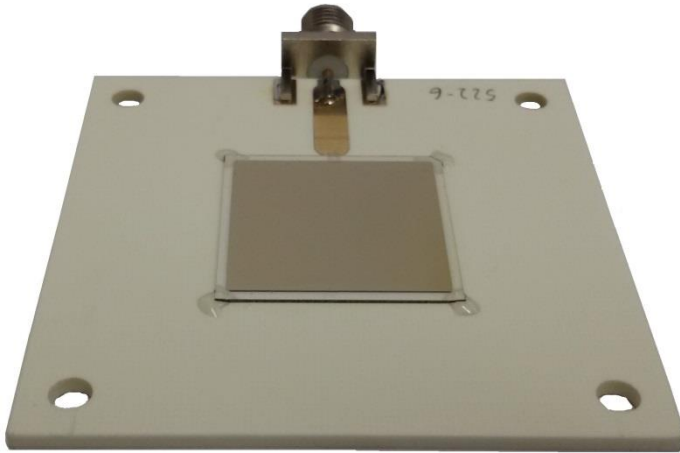
- ❑ ^{12}C @62 MeV/u, 2 pA
- ❑ Collimator, \varnothing 2.5 mm

Detectors:

- ❑ scCVD DD, 3.23x3.23x0.16 mm
- ❑ pcCVD DD, 18x18x0.3 mm
- ❑ SCI, 100x100x0.25 mm
- ❑ SEETRAM, 3 foils each 24 μm

The DDs signals were amplified with the DBA III and then sent either to the oscilloscope (100 ps/bin) or to the discriminator and scaler (VULOM/CAEN) for data acquisition.

Diamond Detectors



pcCVD diamond detector E6_622-5

Thickness	300 μm
Surface Treatment	Oxygen Termination
Electrode Type	Au, 100 nm
Area	20.0x20.0 mm ²
Active Area	18.5x18.0 mm ²



scCVD diamond detector E6_534-8A

Thickness	160 μm
Surface Treatment	Oxygen Termination
Electrode Type	Au, 100 nm
Area	4.2x4.2 mm ²
Active Area	3.23x3.23 mm ²

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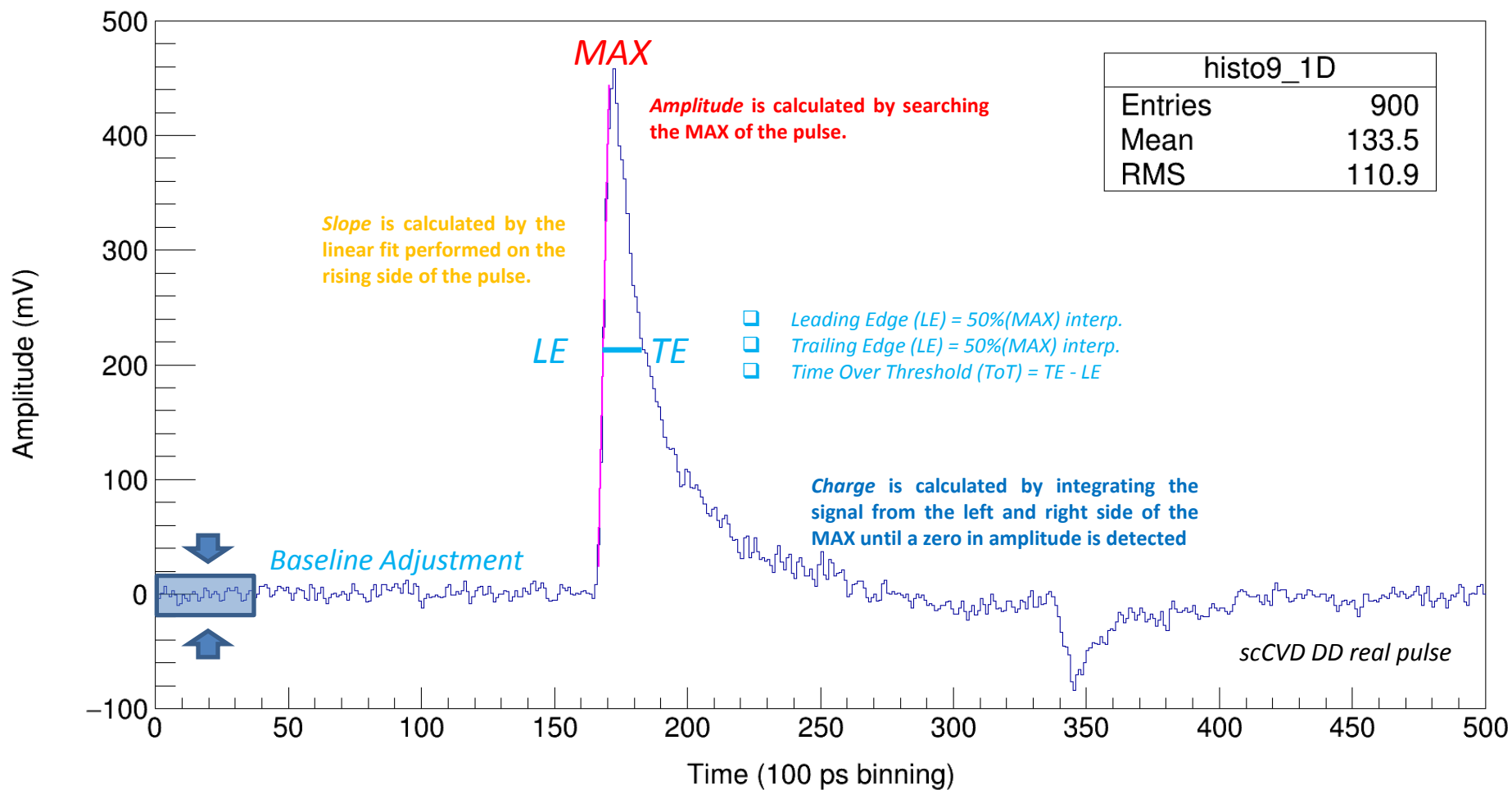
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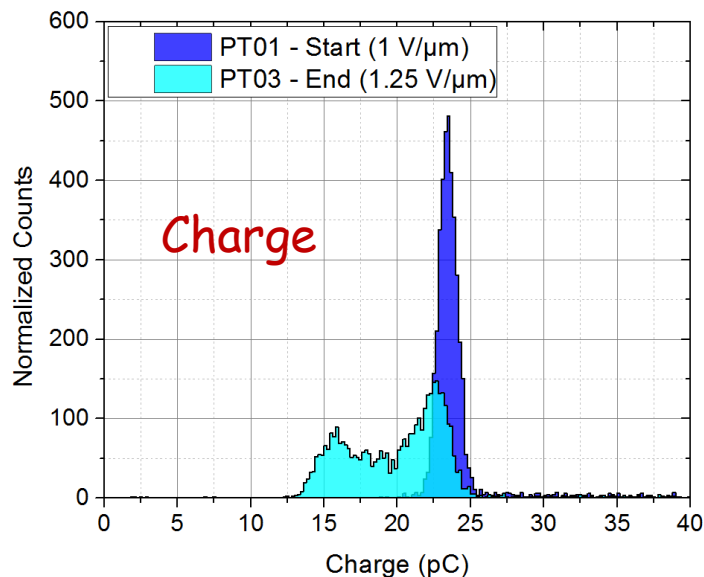
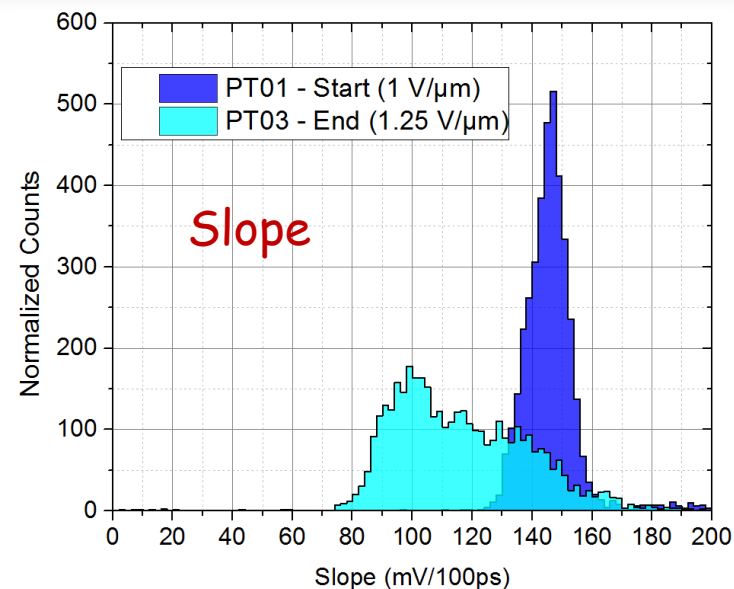
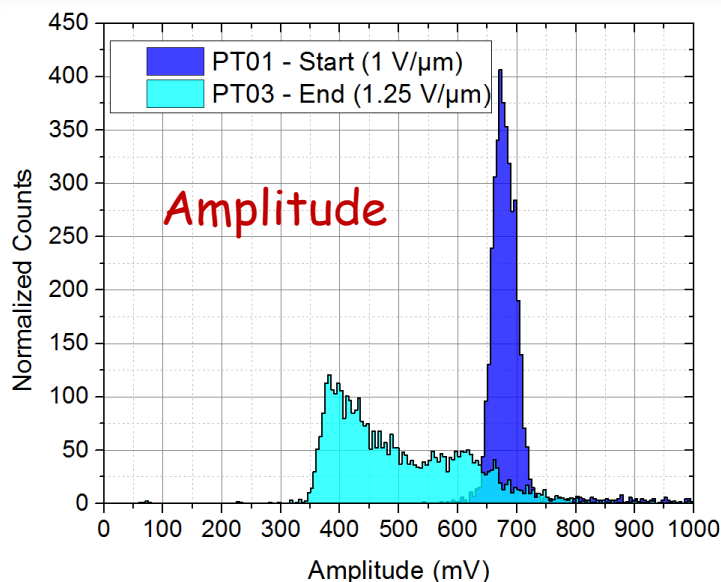
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Waveforms Processing



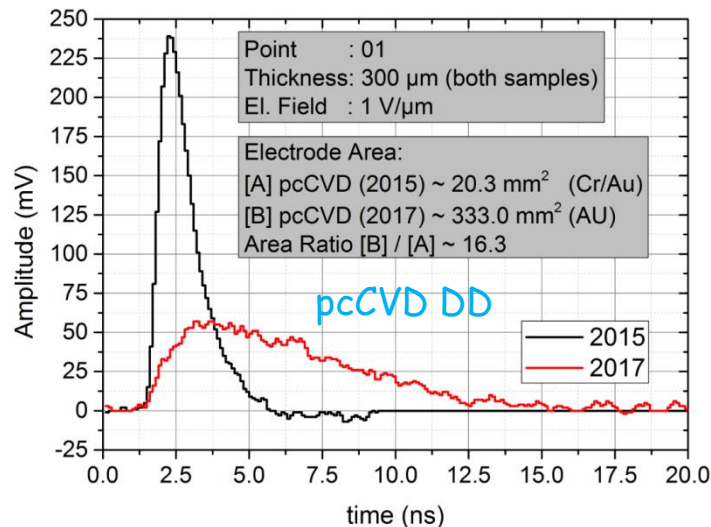
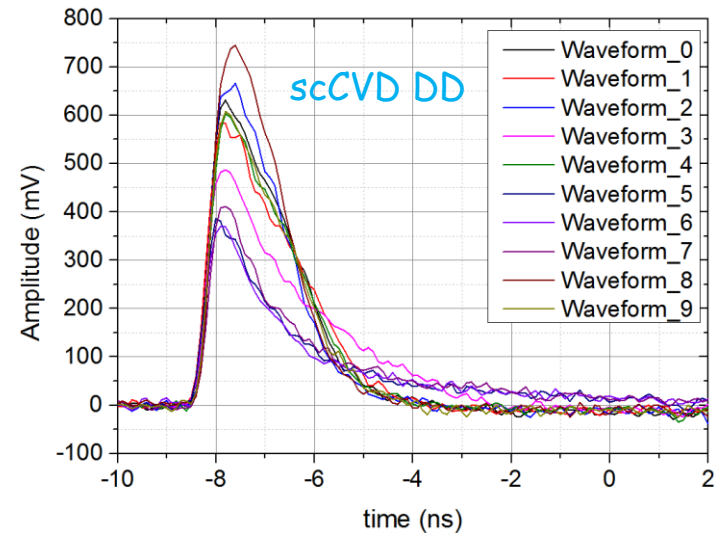
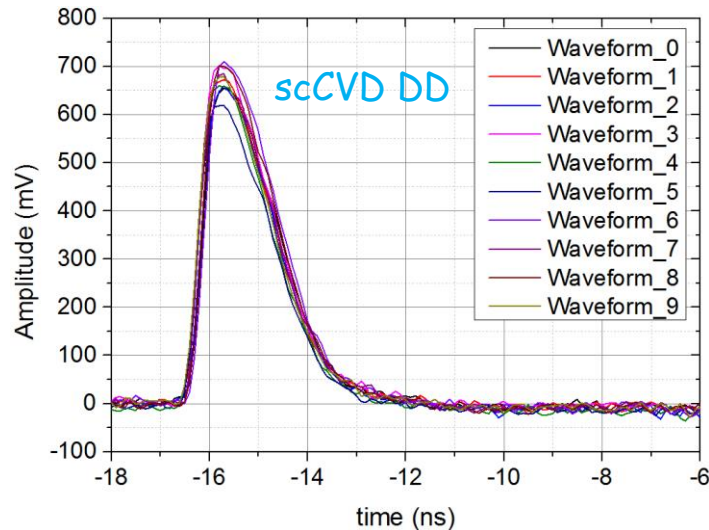
Signal Distributions (scCVD DD)



Remarks:

- ☐ Broadening of the distributions with double peaks;
- ☐ Scintillator distributions still good;
- ☐ Unknown accumulated dose;
- ☐ The minimum dose at which the device was still operating correctly is ~ 20 kGy.

Diamond Detectors Waveforms



Remarks (scCVD DD):

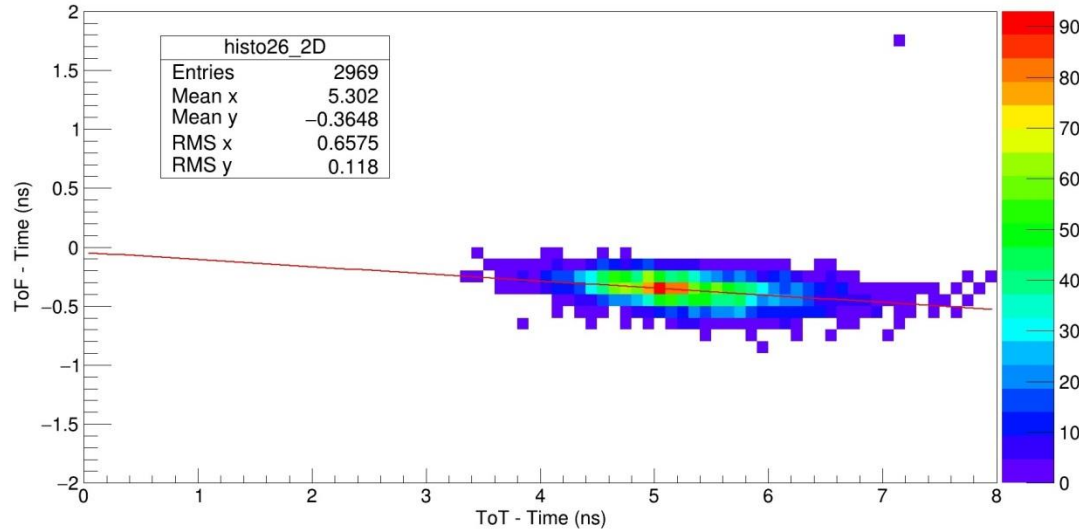
- ❑ broad range of signal amplitudes after beam exposure;
- ❑ different decay times;

Remarks (pcCVD DD):

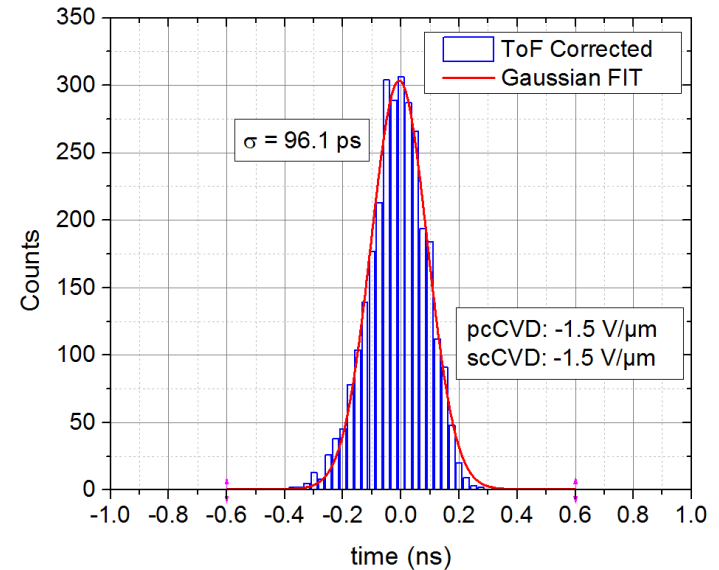
- ❑ larger area electrodes compatible with signals having smaller slope and longer decay times.

ToF Assessment

ToF - pcCVD ToT

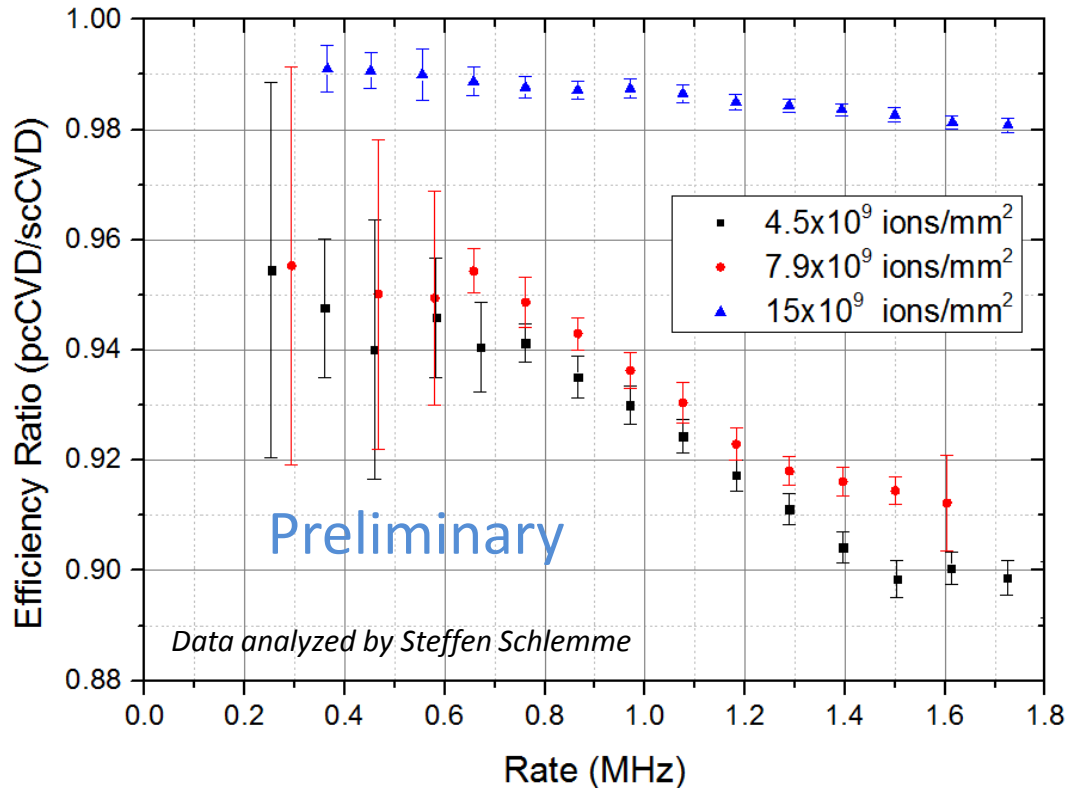


Time of Flight



- ☐ ToF measurements performed for $E = 1$ V/ μ m and $E = 1.5$ V/ μ m on both DIA devices;
- ☐ σ correction obtained by linear fit between ToF and pcCVD DIA ToT distributions;
- ☐ For $E = 1.5$ V/ μ m, correction leads to $\sigma \sim 96$ ps;
- ☐ Only slight improvement (few percent) of σ for $E = 1.5$ V/ μ m.

Efficiency Assessment



- pcCVD DD @ -350V;
- scCVD DD @ -200V;
- Rate given by SEETRAM.

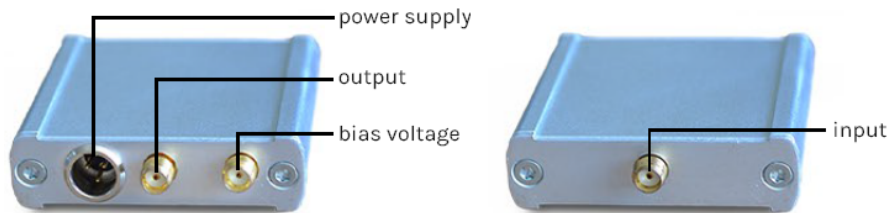
$$E_{\text{pcCVD}} = [94.9 \pm 1.8]\%$$

Efficiency Ratio vs Rate ↓

Efficiency Ratio vs Dose ↑

PA-20 vs DBA III (Specifications)

Type	current preamplifier
Gain	20 dB
Energy range	100 MeV
Bandwidth	1 MHz - 1.5 GHz
Noise RMS	190 μ V (19 μ V input referred)
Input impedance	50 Ω
Output impedance	50 Ω
Input/output coupling	AC coupled
Input polarity	bipolar
Output polarity	bipolar (inverting)
Linear output voltage range	+/- 1 V
Max. bias voltage	+/- 500 V
Power supply	+12 V, 45 mA



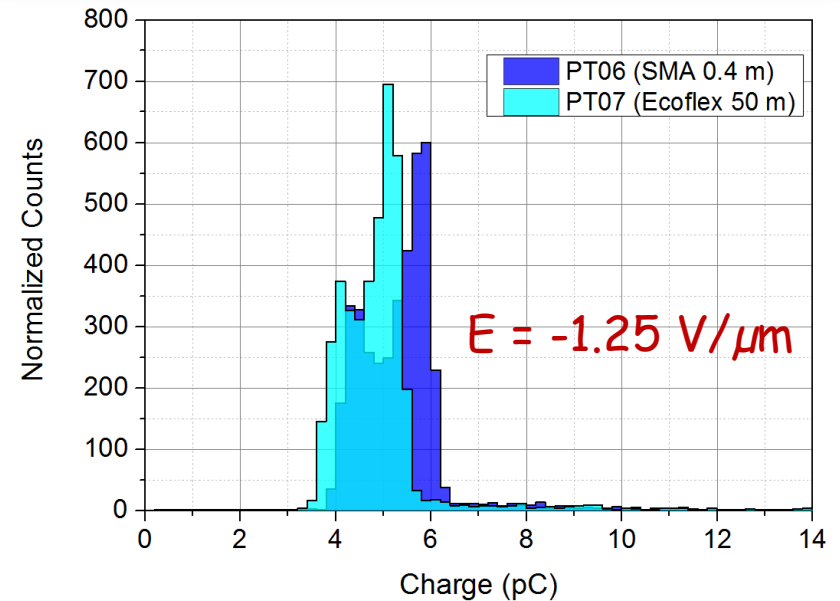
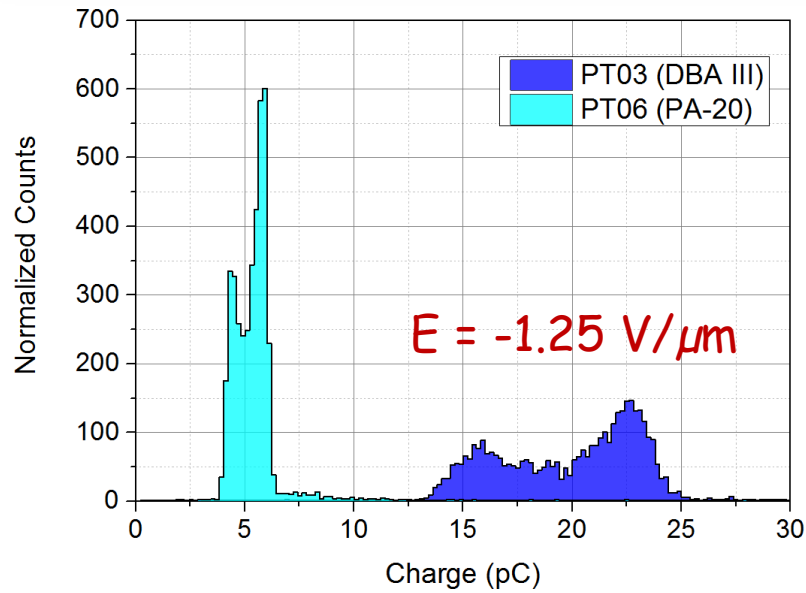
Size	65 mm x 55 mm x 15 mm
Box material	aluminium with RF shielding
Signal connectors	SMA female
HV connector (detector bias)	SMA female
Power connector	mini XLR (power supply cable included)

<http://widebandamplifiers.com> for more info

Type	DBA-III/R
Description	GaAs 2-stage MMIC Inverting Broadband Amplifier
Bandwidth (-3 dB)	0.003 - 2.3 GHz
Gain	+42 dB
Input Impedance	50 Ohms, SWR <1.5
Output Impedance	50 Ohms, SWR <1.5
Noise Figure (Input terminated)	3 dB
Max. Output Power Level	+18dBm / 2V _{peak}
Max. Bias Voltage for the Detector	+/- 2000V, no input protection, the biased input must not be shorted to ground or disconnected !
Power Supply	+12 V, 100mA
Dimensions	Length: 95mm, Width: 47mm, Height 25 mm
Connectors	RF in/out, Bias: SMA; Power: LEMO 4pole



PA-20 Tests (scCVD DD)



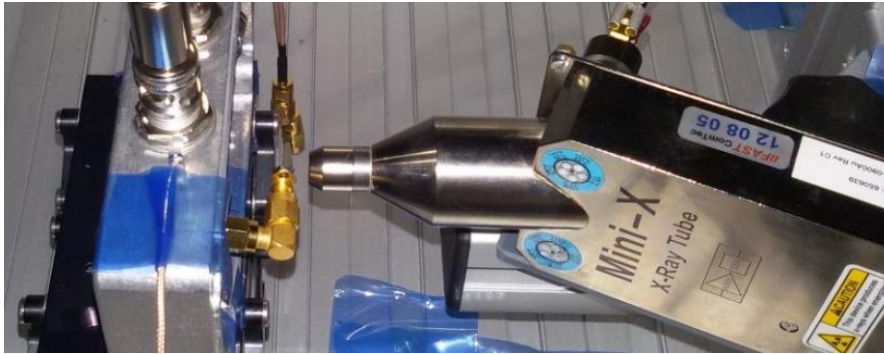
Preamplifier Comparison	File Set	Amp Type	Amplitude (mV)	Slope (mV/100 ps)	Charge (pC)	LE (ns)	Cable (m)	Cable Comparison
	3	DBA III	391.05	97.95	15.65	16.92±0.04	0.4	
	3	DBA III	600.76	137.19	22.84	"	0.4	
	6	PA-20	83.16	16.59	4.41	16.87±0.04	0.4	
	6	PA-20	127.73	22.96	5.53	"	0.4	
	7	PA-20	52.48	7.84	3.83	16.82±0.07	50	
	7	PA-20	84.20	10.73	4.88	"	50	

Data obtained by Gaussian fit of the distributions generated with over 4000 recorded waveforms per set with the scCVD diamond detector.

RG214 cable leads to:

- ☐ decrease of the signal amplitude by ~35%;
- ☐ decrease of the signal slope by factor ~2;
- ☐ LE noisier

Mini X-rays Setup



Target thickness	1 μm (Au)
Tube Voltage	10 to 50kV
Tube Current	5 μA min. / 200 μA max.
Approximate Dose Rate	Dose Rate ~ 1.3 Sv/h @ 30 cm
Collimator	2 mm

Settings

- ☐ Detector distance : ~ 10 mm;
- ☐ Tube voltage : 40 kV;
- ☐ Tube current : 90 μA ;
- ☐ Collimator : 2 mm \varnothing (x-rays flux within a cone of 5°).

The metallic box itself, without detector being connected, has an intrinsic leakage current in the order of 10^{-13} A for ± 500 V voltage applied.

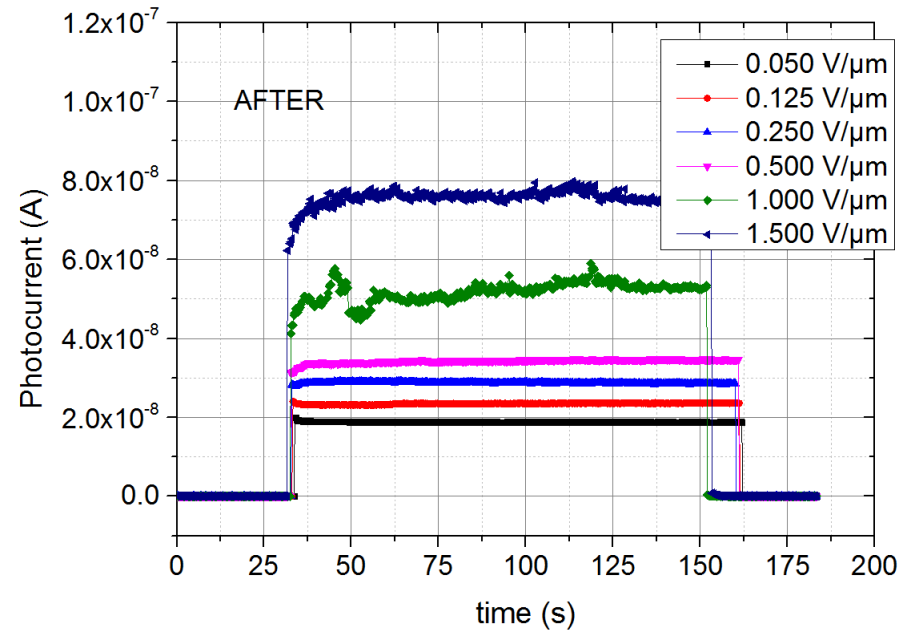
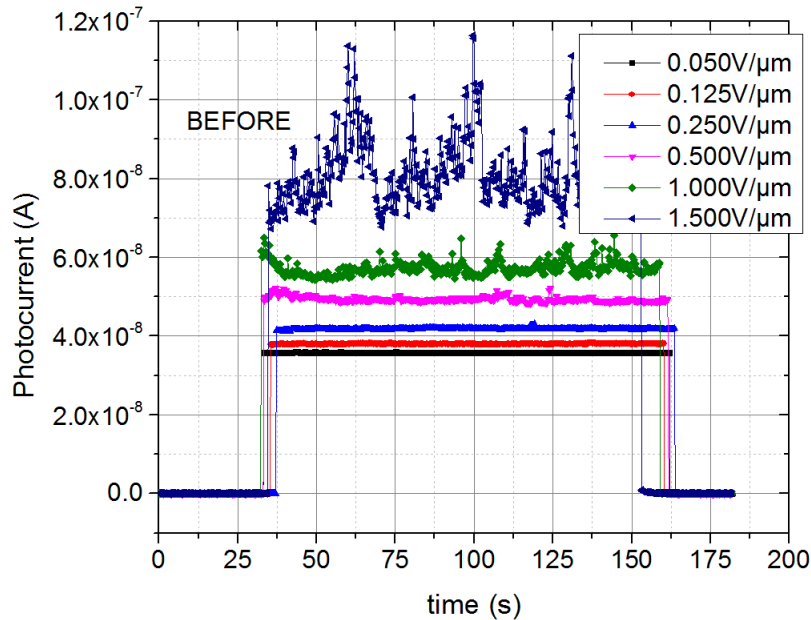
Measurement Program (scCVD DD)

Chronological Order

- ❑ Evaluation of the photocurrent characteristics (dynamic response and fluctuation of the signal) for different voltages applied;
- ❑ Measurement of the I - V characteristics of the leakage current;
- ❑ Long term measurement (over 160 minutes) to check the stability of the detector signal at different stages.

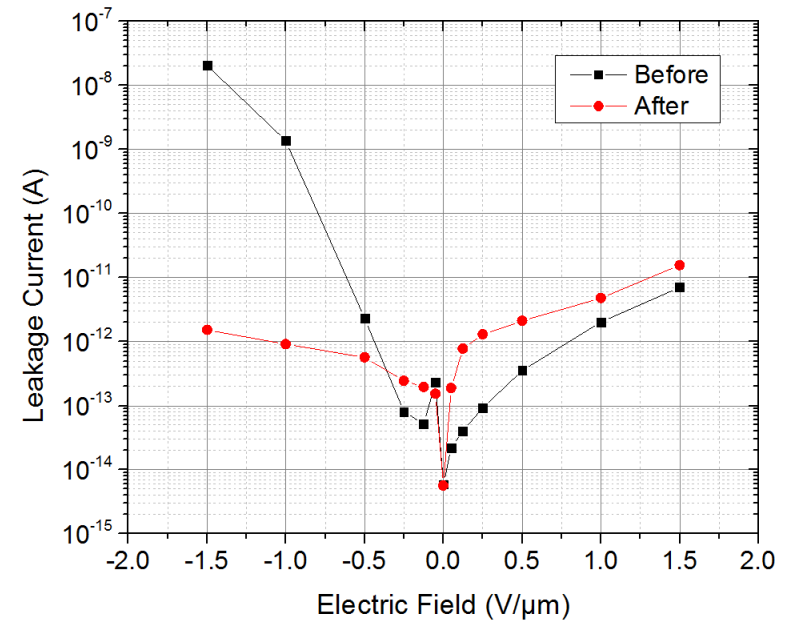
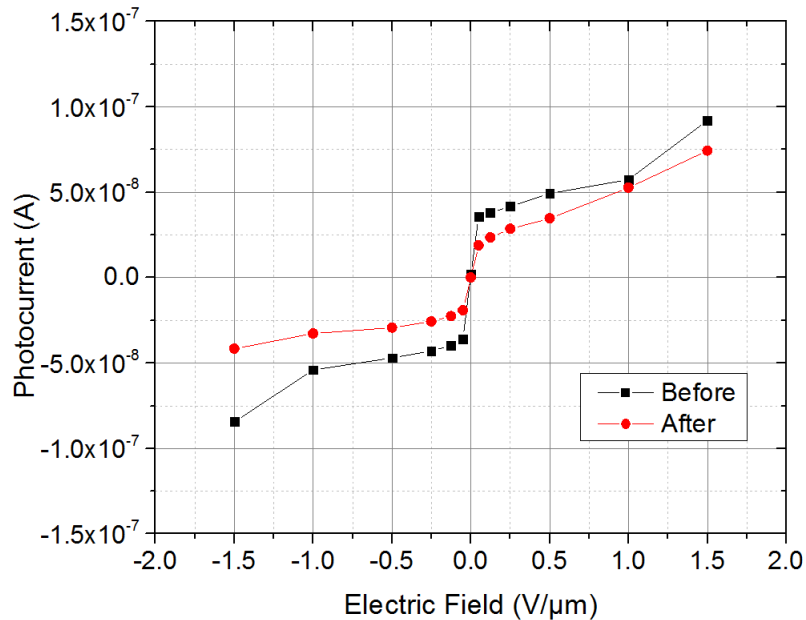
Bias (V)	El. Field (V/ μ m)
-240	-1.5
-160	-1
-80	-0.5
-40	-0.25
-20	-0.125
-8	-0.05
0	0
8	0.05
20	0.125
40	0.25
80	0.5
160	1
240	1.5

Dynamic Response & Signal Fluctuations



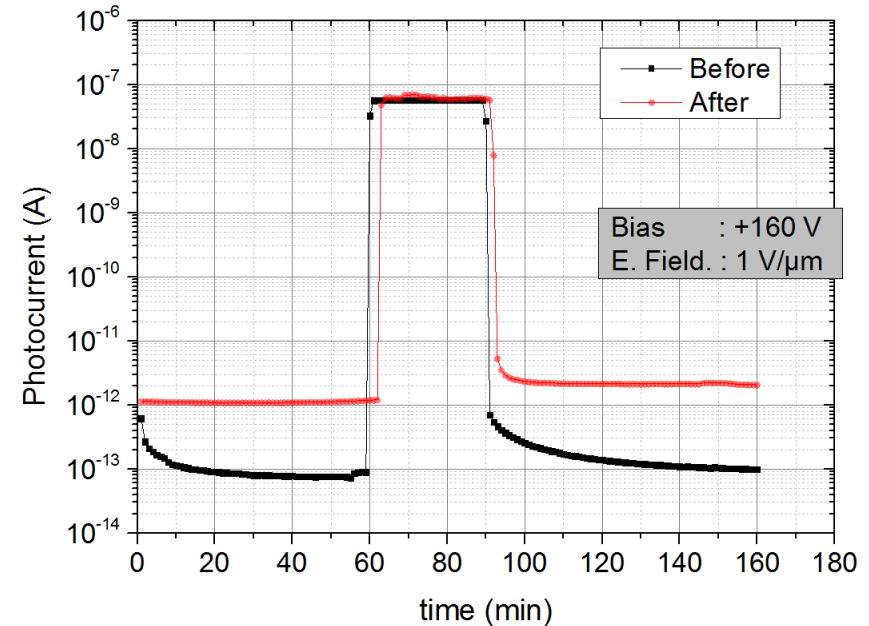
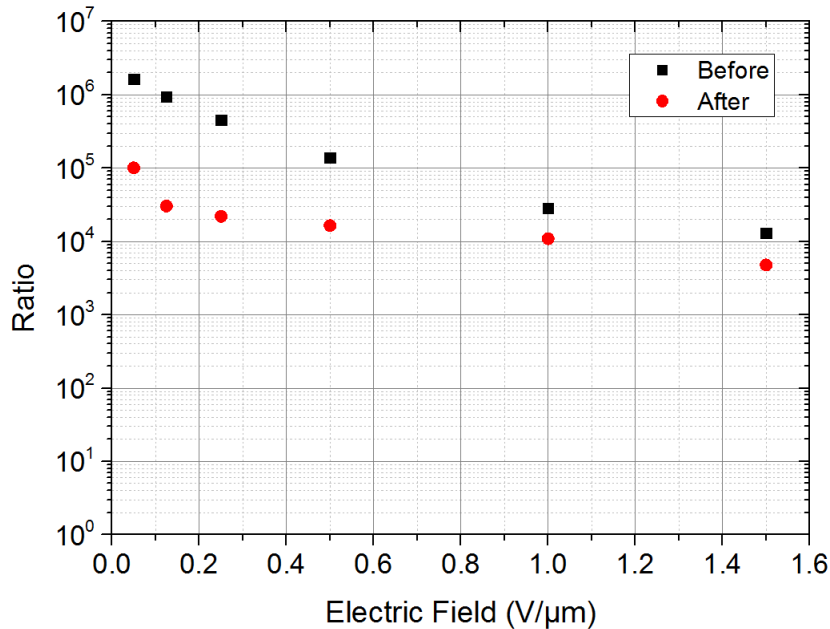
- ❑ Generally, similar behaviour;
- ❑ Slightly lower value of the photocurrent (AFTER) especially at lower voltages;
- ❑ The detector exhibits faster saturation (x-rays ON) of the signal for $E < 1 \text{ V}/\mu\text{m}$;
- ❑ Instability of the signal for $E > 0.5 \text{ V}/\mu\text{m}$;
- ❑ Instability decreases for $E > 0.5 \text{ V}/\mu\text{m}$ (AFTER)

Photocurrent and Leakage Current



- ❑ Leakage current calculated as average over ten data points recorded just before switching on the x-rays source;
- ❑ Photocurrent calculated as average over ten data points recorded just before switching off the x-rays;
- ❑ Leakage current slightly increases for $E > 0$ while decreases a few order of magnitudes for high values of E .

SNR & Long Term Measurements



- ❑ The SNR differs by one order of magnitude and becomes smaller for $E > 1 \text{ V}/\mu\text{m}$;
- ❑ The SNR decreases while increasing E since the leakage current increases more compared to the photocurrent;
- ❑ Long term measurement at $E = 1 \text{ V}/\mu\text{m}$, {60 minutes [leakage current]; 30 minutes [x-rays tube ON]; 70 minutes [photocurrent decay]};
- ❑ 160 points whose value corresponds to an averaged electric current over one minute of measurement;
- ❑ Strong instability of the signal.

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- ❑ As already observed in the 2015, the scCVD diamond detector shows deterioration of the signal properties after exposure to irradiation;
- ❑ The large electrode area of the pcCVD device influenced its performance;
- ❑ For beam rate < 1 MHz, the efficiency of the pcCVD diamond detector is $> 94\%$;
- ❑ The new preamplifier PA-20 was successfully tested;
- ❑ The 50 m cable influences the ToF and the signal properties of the scCVD device. Detector counting can be compensated by adjustments of the electronics settings;
- ❑ The x-rays tests confirms the worsening of the scCVD diamond detector signal properties;
- ❑ Signal instability due to high electric field applied is still an issue to be solved.

Acknowledgements

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Thank you!

